

Strong enhancement of superconductivity at high pressures within the charge-density-wave states of 2H-TaS₂ and 2H-TaSe₂

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We present measurements of the superconducting and charge density wave critical temperatures (T_c and T_{CDW}) as a function of pressure in the transition metal dichalcogenides 2H-TaSe₂ and 2H-TaS₂. Resistance and susceptibility measurements show that T_c increases from temperatures below 1 K up to 8.5 K at 9.5 GPa in 2H-TaS₂ and 8.2 K at 23 GPa in 2H-TaSe₂. We observe a kink in the pressure dependence of T_{CDW} at about 4 GPa that we attribute to the lock-in transition from incommensurate CDW to commensurate CDW. Above this pressure, the commensurate T_{CDW} slowly decreases coexisting with superconductivity within our full pressure range.

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INTRODUCTION

The near absence of reports on superconductivity in graphene and related single layer systems is notorious, given the large efforts devoted presently to these materials. Only recently have superconducting signatures in doped graphene sheets[1, 2] and Ising superconductivity in trigonal prismatic monolayer MoS₂[3, 5] and NbSe₂[4] been observed. Few-layer devices have been also made of transition metal dichalcogenides (2H-TX₂, with T=Nb, Ta and X=S, Se), which crystallize in a hexagonal arrangement of transition metal atoms separated by the chalcogen. Single molecular layers, formed by hexagonal T-X groups, show opposing tendencies with decreasing thickness—a reduction of superconducting T_c in 2H-NbSe₂ and an increase in 2H-TaS₂[6–10].

Layered materials are generally very sensitive to modifications of their lattice parameters[11–19]. To understand their superconducting T_c , we need to address the interplay between superconductivity and the charge density wave (CDW) and how this interplay evolves when varying the lattice parameters.

It has been argued [11, 20] that superconductivity and CDW strongly interact in the 2H-TX₂. Initial discus-

sions pointed out that there was a mutually exclusive interaction. Indeed, T_c decreases and T_{CDW} increases when the the lattice parameter a/c ratio decreases as we pass from 2H-NbS₂ ($T_c = 6$ K and $T_{CDW} = 0$ K), 2H-NbSe₂ ($T_c = 7.2$ K and $T_{CDW} = 30$ K), 2H-TaS₂ ($T_c = 1$ K and $T_{CDW} = 80$ K) and 2H-TaSe₂ ($T_c = 0.1$ K and $T_{CDW} = 120$ K). On application of pressure in 2H-NbSe₂, the CDW disappears above 5 GPa and T_c increases slightly up to 8.5 K at 10 GPa[12, 18], pointing out an exclusive interaction too. Measurements of the superconducting density of states and of vortex core shapes in 2H-NbSe₂ show that the superconducting gap of 2H-NbSe₂ is strongly shaped by the CDW and it has been argued that the CDW decreases the gap value along certain directions in real space[21]. Angular resolved photoemission also shows interesting correlations between superconducting and CDW Fermi surface features. If these are cooperative or exclusive is, however, not clearly established when taking different photoemission measurements into account[22, 23]. Thus, most experiments point out that, particularly from data in 2H-NbSe₂, the interaction seems to be of competing nature. The mutual interaction between superconductivity and magnetism is debated in the cuprate compounds, where

cooperative interactions have been discussed[24]. Here we find that, unexpectedly, CDW and superconductivity coexist in a large part of the phase diagram when applying pressure to the Ta based 2H-TX₂, namely 2H-TaS₂ and 2H-TaSe₂.

In the compounds with largest interlayer separation and highest CDW transition temperatures, 2H-TaS₂ and 2H-TaSe₂, the CDW and superconducting phase diagrams have been studied up to 4 GPa. The superconducting T_c increases in both compounds, up to about 2.5 K in 2H-TaS₂ and 0.4 K in 2H-TaSe₂[25]. In 2H-TaS₂, the resistivity vs temperature as a function of pressure shows that the CDW appearing below 80 K at ambient pressure decreases down to about 66 K at 3.5 GPa in 2H-TaS₂[11, 26, 27]. In 2H-TaSe₂, the ambient pressure phase diagram consists of an incommensurate CDW (ICDW) appearing at 120K and a lock-in transition at 90K to a commensurate CDW (CCDW). There is a reentrant lock-in transition with pressure[29]. The incommensurate CDW occupies the whole temperature range above 2 GPa, but, above 4 GPa, it locks to the lattice and becomes again commensurate [29–34]. Here we study the effect of pressure up to 25GPa on superconductivity and charge density waves in 2H-TaS₂ and 2H-TaSe₂. We find that the CDW does not disappear up to the highest pressures studied and that T_c increases considerably up to close to 9 K in both compounds.

EXPERIMENTAL

To make a comparative study of both T_{CDW} and T_c under pressure we measure the magnetic susceptibility and the resistivity of small samples. The samples were grown using vapour transport and the politype purity of the 2H phase was checked by powder X-ray diffraction[26]. To this end, samples of synthesized crystals were ground and loaded inside a capillary ready for powder X-Ray diffraction (performed in ambient conditions). Indexation of the reflections of the powder pattern by assuming a hexagonal symmetry allowed for the identification of a single phase with the following unit cell parameters: $a = b = 3.3137(2)$ Å, $c = 12.076(1)$ Å for 2H-TaS₂ and $a = b = 3.43910(5)$ Å, $c = 12.7067(2)$ Å for 2H-TaSe₂. The Le Bail refinement of the room temperature powder pattern is in agreement with that described for the 2H phases of TaS₂ and TaSe₂ crystals. To measure the susceptibility, we use a diamond anvil cell with a pressure transmitting medium of a methanol-ethanol mixture (4:1), which is considered to yield quasi-hydrostatic conditions up to the pressures of interest in our experiment[18, 36]. Pressure was determined by the ruby fluorescence method [37]. We measure on small single crystalline samples cut into parallelepipeds of size about $100 \times 100 \times 30 \mu\text{m}^3$. The susceptibility is obtained by a conventional AC method using a transformer and a

lock-in amplifier[18]. For the resistance we use a Bridgman pressure cell with steatite as the pressure transmitting medium [38]. Platinum wires were passed through the pyrophyllite gasket. Samples are cut into pieces of approximate size of $\sim 100 \times 400 \times 60 \mu\text{m}^3$ and contacted to the platinum leads in the pressure cell. The temperature was controlled by a motor introducing gradually into the cryostat the cell attached to a cane. The electrical resistance measurements were performed using a Keithley 220 source and a Keithley 2182 nanovoltmeter. Two samples were measured simultaneously giving the same results. We could not appropriately determine the volume of samples nor the geometrical factor. Thus, we provide relative temperature variations of susceptibility and resistance.

Fig. 1 displays the susceptibility and resistance versus temperature curves obtained at different pressures at low temperatures. We determine T_c from the onset of the superconducting resistive and magnetic transition curves, defined as the intersection of two tangents, one to the flat portion of the curve above and the second to the steepest variation in the signal below the superconducting transition. In all cases we obtain sharp transitions, providing an unambiguous determination of the superconducting T_c . Sometimes, we observe in the resistance measurements a small non-zero residual value in the superconducting phase, which we attribute to two contacts touching each other at one side of the sample in the pressure cell. This does not influence the determination of T_c .

RESULTS

The evolution of T_{CDW} under pressure was determined by calculating the temperature derivative of the resistance, $dR(T)/dT$, from the measured resistance vs temperature curves. In Fig. 2, we show $dR(T)/dT$ for different pressures. The development of the CDW produces a gap on the Fermi surface that causes a sudden increase in the resistance which induces a downward peak in $dR(T)/dT$ [39]. Their position in the curves are signalled on Fig 2 by small arrows. The obtained pressure dependence of T_c and T_{CDW} is shown in Fig. 3.

In 2H-TaSe₂, we find that pressure provokes an increase of T_c , with a slope of 0.58 K/GPa, between 2 and 8 GPa. The maximum is attained at $T_c = 8.2$ K at the pressure of 23 GPa. On the other hand, T_{CDW} , which signals, as discussed above, an ICDW transition, decreases slowly to about 4 GPa. At 4 GPa we observe a jump. On further compression, T_{CDW} continues its rather slow decrease reaching a value of ~ 90 K at 20GPa.

2H-TaS₂ shows a similar behavior. We find an initial slope $dT_c/dP = 1.05$ K/GPa below 6 GPa, which then slows down to 0.45 K/GPa, between 6 and 9.5 GPa. At low pressure, T_{CDW} decreases slowly, similarly to previ-

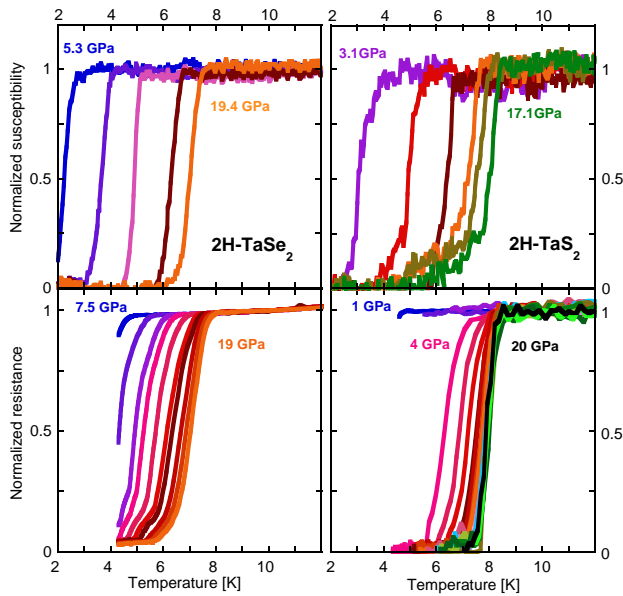


FIG. 1. Upper panels: Susceptibility of 2H-TaSe₂ (left panel) and 2H-TaS₂ (right panel) as a function of temperature for several applied pressures (5.3, 8.1 11.7 16.7 and 19.4 GPa for 2H-TaSe₂ and 3.1 5.8 7.9 9.8 14.8 and 17.1 GPa for 2H-TaS₂). Susceptibility has been normalized to the value found at 10 K, and the low temperature value has been modified to give zero. Lower panels: Resistance as a function of temperature for 2H-TaSe₂ (left panel) and for 2H-TaS₂ (right panel) for several applied pressures (from 7.5 to 15 by 1.5 GPa step and then every GPa up to 19 GPa for 2H-TaSe₂ and every GPa from 1 to 20 GPa for 2H-TaS₂). The resistance has been normalized to its value at 10 K.

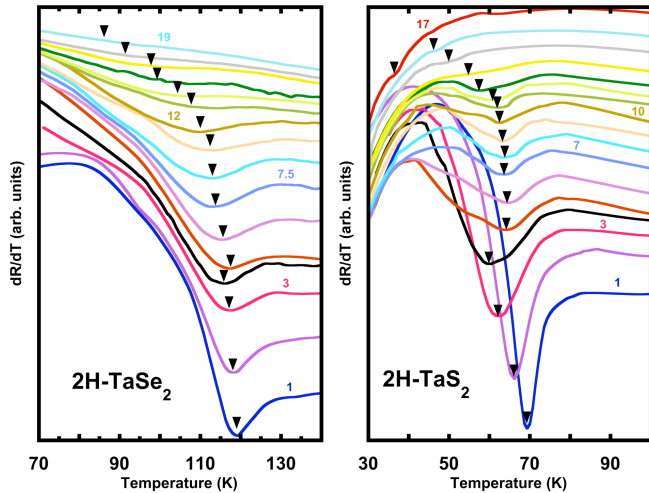


FIG. 2. Derivative of the resistance close to the CDW ordering temperature for respectively 2H-TaSe₂ (left panel) and 2H-TaS₂ (right panel) for different pressures (1,2,3,4,5,6,7.5,9,10.5,12,13.5,15,16,17,18 and 19GPa (left) and every GPa from 1 to 17 GPa (right)). Curves are shifted in the y-axis for clarity. An arrow is used to mark the position where we take T_{CDW} to give the pressure dependence discussed in Fig 3.

ous results[26]. At 4 GPa we observe a sharp jump, similar to the one observed in 2H-TaSe₂. Above the jump, T_{CDW} continues its slow decrease down to ~ 40 K at 17GPa.

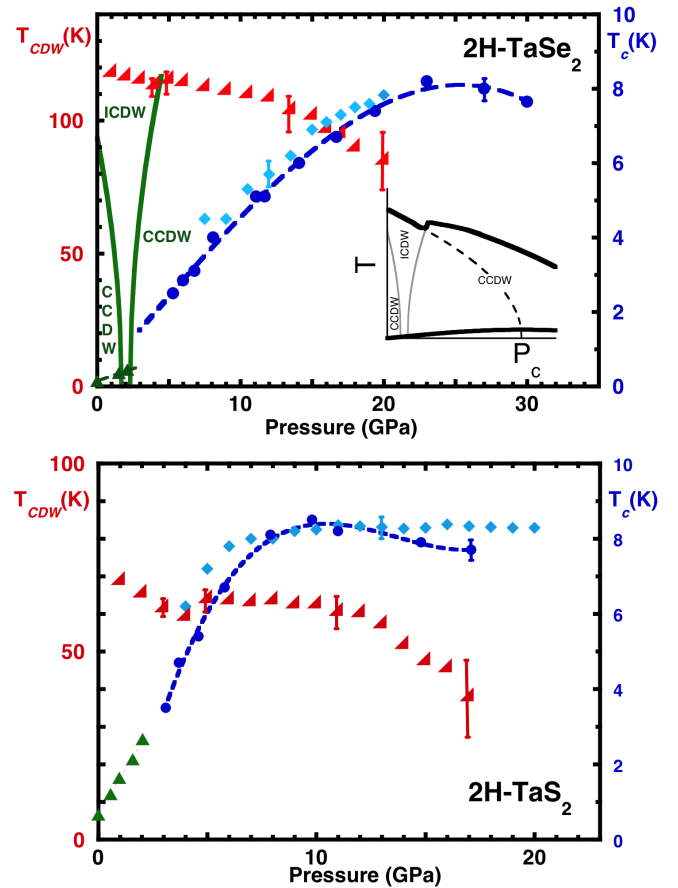


FIG. 3. Phase diagram of the superconducting transition obtained from susceptibility (blue full circles), resistance (light blue losanges), and of the CDW transition (red triangles). Full triangles at low pressures have been obtained from Smith et al. [25]. Typical error bars are shown. Blue lines are guides to the eyes. Green dashed lines in the top panel are the positions of the CDW as found in previous works for 2H-TaSe₂[26, 29, 30]. Inset: proposed phase diagram for both compounds. Black dashed lines are extrapolations of the low pressure range data (see text).

DISCUSSION AND CONCLUSIONS

Within the well-proven Bilbro-McMillan approach[40], the SC involves the portion of carriers which are not gapped by CDW, explaining their mutual competition. In quasi-1D systems, CDW's are originated by strong nesting of the parallel FS. Application of pressure destroys the CDW at a critical pressure P_c , where T_c attains its maximum value[41–44]. While the loss of Fermi surface portions due to nesting dominates the interplay between CDW and superconductivity in quasi-1D systems, the situation is more involved in quasi-2D systems. Due to the quasi-cylindrical nature of the 2D FS's, the nesting anomalies are much weaker[45] and then electron-phonon coupling is more important in creating CDWs than in quasi-1D systems [31, 46–50]. The interplay between competing electronic and elastic degrees of freedom produces then minima in the free energy landscape that

easily favor different kinds of CDW (commensurate or incommensurate) when modifying pressure and temperature.

For 2H-TaSe₂, the jump in T_{CDW} observed at about 4 GPa agrees with the previously reported pressure induced lock-in transition into a CCDW[29] (right green line in Fig. 3). Such a peak in the variation of density wave transition temperatures with pressure has been observed in other materials [52, 53] and have been unequivocally ascribed to transitions from an incommensurate to a commensurate state. McMillan explained the first order nature of the incommensurate / commensurate transition temperature driven by a Ginzburg Landau analysis [51]. By analogy, we expect that the pressure driven incommensurate/commensurate transition is also a first order transition and induce a jump in the $T_{CDW}(P)$ phase diagram.

The behaviour at ambient pressure for both compounds is similar. At high temperature they show a transition to an ICDW, with a lock-in transition to an CCDW at lower temperatures [27–29]. We can then speculate that the jump around 4GPa in both 2H-TaSe₂ and 2H-TaS₂ are due to the same phenomenon. That would imply that the ICDW in 2H-TaS₂ locks to the lattice with increasing pressure. We include this possibility in the proposed general phase diagram shown in the insert of Fig. 3.

The weak pressure dependence of T_{CDW} at higher pressures indicates, on the other hand, that the CDW in this pressure range is remarkably robust to a reduction of the lattice parameters. This is not possible to explain within a pure nesting scenario, because band structure and the nesting condition are extremely sensitive to pressure. On other hand, in the simplest lattice scenario through an e-ph coupling, theories have to reconcile the absence of pressure dependence of T_{CDW} with the phonons hardening due to pressure.

It is interesting to discuss a recent model proposed to explain the CDW in the 2H transition metal dichalcogenides[54]. It considers that the CDW transition takes the form of a phase transition in a system of interacting Ising pseudo-spins. These can be associated to the six transition metal atoms lying on the vertices of the in-plane hexagon described in Ref. [47]. These might have a tendency to cluster in such a way as to form an inverse-star towards the transition metal atom at the center of the hexagon. This type of distortion has locally an intrinsic degeneracy, i.e. the transition metal atoms can choose between two inverse-stars with the same type of displacement. By analogy with an up and down Ising ferromagnet, this is called a Ising pseudo-spin model. Thus, order is only short ranged and the development of a macroscopic static distortion corresponds to an ordering of the Ising pseudo spins[55]. This order-disorder transition is characterized by the absence of unstable zero energy phonon softening at the transition, as is confirmed

by the reported non-zero soft mode for 2H-TaSe₂[35]. Furthermore, the idea of pre-existing disordered deformations stems from the observation of a gap 5 times larger than the expected from weak-coupling formula[56] and could be used to explain the robustness of the CDW at the higher pressures. It would imply, though, that the model describes better the transition metal dichalcogenides with large interlayer separation, 2H-TaSe₂ and 2H-TaS₂, than 2H-NbSe₂. In the latter compound the CDW has a lower critical temperature (30 K) and disappears already at 5 GPa[12, 14].

Regarding the superconductivity, our measurements show that T_c is strongly enhanced within the commensurate high pressure CDW phase. The increase in T_c might be a consequence of phonon hardening or of Fermi surface induced changes with pressure. But it is not straightforward to think of a scenario where such features act on superconductivity independently to the CDW. A possibility is that both phenomena involve widely different parts of the Fermi surface associated to the absence or small interband correlations.

It is interesting to note that the extrapolation of the low pressure (below the jump) behavior of the ICDW up to higher pressures using a mean field approach $T_{ICDW} = T_{ICDW}^0 \sqrt{\frac{P_c - P}{P_c}}$ (where T_{ICDW}^0 is the ambient pressure ICDW transition) leads to values for T_{ICDW}^0 becoming zero at a pressure P_c roughly when the $T_c(P)$ curve ceases to increase in both materials. In the past, a mean field power law has been used for the low pressure commensurate transition in 2H-TaSe₂ [30, 57]. We have tentatively highlighted this aspect in the inset of Fig. 3. Although the extrapolation is, of course, connected with very large errors, it invites the speculation that there might be a mutually exclusive relation between incommensurate CDW and superconductivity. Note, however, that the Bilbro-McMillan approach discussed above in relation with the competition between incommensurate CDW and superconductivity does no longer apply when the incommensurate CDW has passed a transition into a commensurate CDW.

It is worth to note that the phase diagrams of 2H Ta-based dichalcogenides are in sharp contrast from that of other transition metal dichalcogenides such as 1T-TiSe₂, where superconductivity is observed at the vicinity of the pressure range of ICDW [17, 58] or 2H-NbSe₂, where T_c is only moderately affected by the pressure[12, 18]. In this last compound, the insensitivity of the superconducting critical temperature to the CDW transition is due to the fact that high energy optical phonon modes have a strong contribution to the Eliashberg function, whereas the low-energy longitudinal acoustic mode that drives the CDW transition barely contributes to superconductivity[59].

We conclude that understanding the value of T_c in layered materials requires studying modifications of band-structure, phonon dispersion and electron phonon cou-

pling. Here we have shown that T_c can considerably increase within a CDW, by more than an order of magnitude.

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